

RoHS Compliant Product

A suffix of "C" specifies halogen free

## FEATURES

- Planar MOS Schottky technology
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

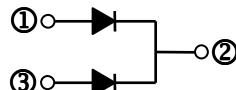
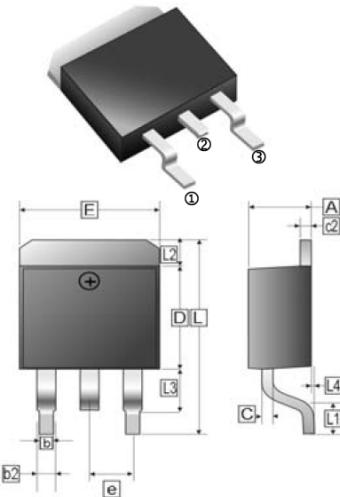
## MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any

## PACKAGE INFORMATION

Package	MPQ	Leader Size
TO-263	0.8K	13 inch

**TO-263(D<sup>2</sup>-PACK)**



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	4.00	4.87	c2	1.07	1.65
b	0.51	1.01	b2	1.34	REF
L4	0.00	0.30	D	8.0	9.65
C	0.30	0.74	e	2.54	REF
L3	1.50	REF	L	14.6	16.1
L1	2.5	REF	L2	1.27	REF
E	9.60	10.67			

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, de-rate current by 20%).

Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	60	V
Working Peak Reverse Voltage	V <sub>RSM</sub>	60	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	60	V
Maximum Average Forward Rectified Current	I <sub>F</sub>	15	A
(Per Device)		30	
Peak Forward Surge Current, 8.3 ms single half sine-wave	I <sub>FSM</sub>	250	A
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	10000	V / $\mu$ s
Typical Thermal Resistance	R <sub>θJC</sub>	3	°C /W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-40~150	°C

## ELECTRICAL CHARACTERISTICS

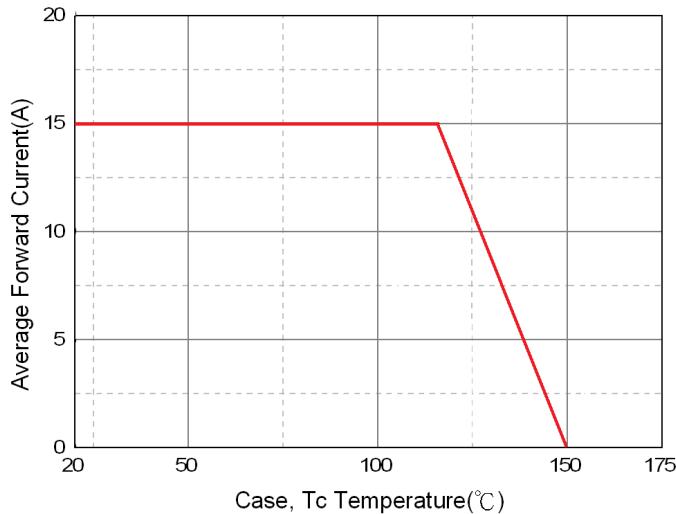
Parameter	Symbol	Typ.	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V <sub>F</sub>	0.37	0.39	V	I <sub>F</sub> = 3A, T <sub>J</sub> = 25°C
		0.41	0.46		I <sub>F</sub> = 5A, T <sub>J</sub> = 25°C
		0.49	0.53		I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C
		0.58	0.61		I <sub>F</sub> = 15A, T <sub>J</sub> = 25°C
		0.56	-		I <sub>F</sub> = 15A, T <sub>J</sub> = 125°C
Maximum DC Reverse Current at Rated DC Blocking Voltage <sup>2</sup>	I <sub>R</sub>	-	0.5	mA	T <sub>J</sub> =25°C
		-	20		T <sub>J</sub> =100°C
Typical Junction Capacitance <sup>1</sup>	C <sub>J</sub>	520	-	pF	

NOTES:

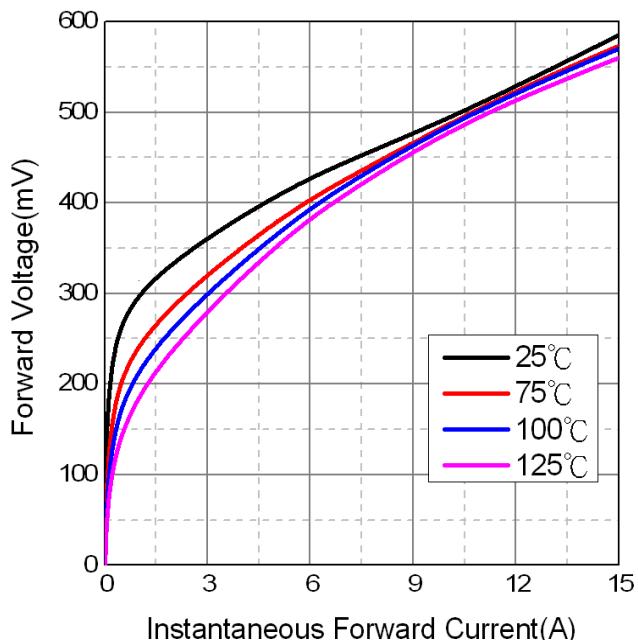
1. Measured at 1MHz and applied reverse voltage of 5.0V D.C.
2. Pulse Test : Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

## RATINGS AND CHARACTERISTIC CURVES

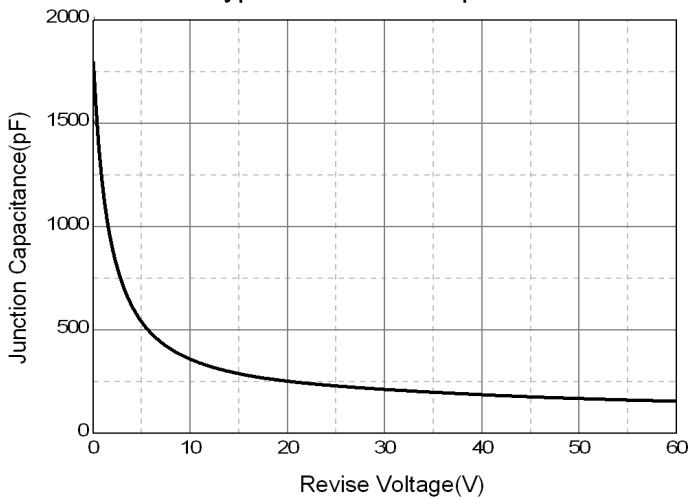
Typical Forward Current Derating Curve



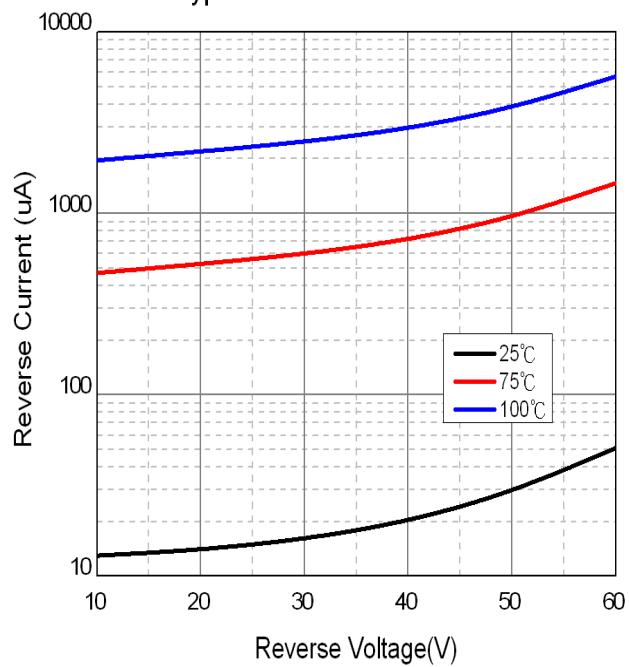
Typical Forward Characteristic



Typical Junction Capacitance



Typical Reverse Characteristic



Maximum Non-Repetitive Forward Surge Current

